



GPBP7038

BIDIRECTIONAL PHASE CONTROLLED SCR

High reliability operation

DC power supply

AC drives

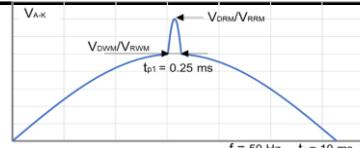
VOLTAGE UP TO 6500 V

AVERAGE CURRENT 380 A

SURGE CURRENT 7 kA

BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
V _{RMM}	Repetitive peak reverse voltage, max	6500 V
V _{DRM}	Repetitive peak off-state voltage, max	6500 V
V _{RWM}	Crest working forward voltage, max	5600 V
V _{DWM}	Crest working reverse voltage, max	5600 V
V _{RSM}	Non-repetitive peak reverse voltage	6500 V
V _{DSD}	Non-repetitive peak off-state voltage	6500 V
I _{DRM}	Repetitive peak off-state current, max.	100 mA
I _{IRRM}	Repetitive peak reverse current, max.	100 mA



ON-STATE CHARACTERISTICS

I _{T(AV)}	Average on-state current	Sine wave, 180° conduction, Th = 55 °C	380 A
I _{T(RMS)}	R.M.S. on-state current	Sine wave, 180° conduction, Th = 55 °C	597 A
I _{TSM}	Surge on-state current	Non rep. half sine wave, 50 Hz, V _R = 0 V, T _j = T _{jmax}	7.0 kA
I _t	I ² t for fusing coordination		245 kA ² s
V _{T(TO)}	Threshold voltage	T _j = T _{jmax}	1.29 V
r _T	On-state slope resistance	T _j = T _{jmax}	1.89 mΩ
V _{TM}	Peak on-state voltage, max	On-state current I _T = 500 A, T _j = T _{jmax}	2.24 V
I _H	Holding current, max	T _j = 25 °C	150 mA
I _L	Latching current, typ	T _j = 25 °C	1000 mA

TRIGGERING CHARACTERISTICS

V _{GT}	Gate trigger voltage	T _j = 25 °C, V _d = 5 V	3 V
I _{GT}	Gate trigger current	T _j = 25 °C, V _d = 5 V	300 mA
V _{GD}	Non-trigger voltage	V _d = 67% V _{RMM} , T _j = T _{jmax}	0.25 V
P _{GM}	Peak gate power dissipation	Pulse width 100 μs	150 W
P _{GA(V)}	Average gate power dissipation		2 W
I _{FGM}	Peak gate current		10 A
V _{FGM}	Peak gate voltage (forward)		25 V
V _{RGM}	Peak gate voltage (reverse)		5 V

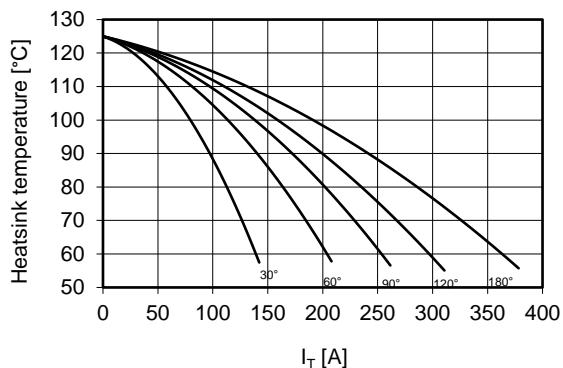
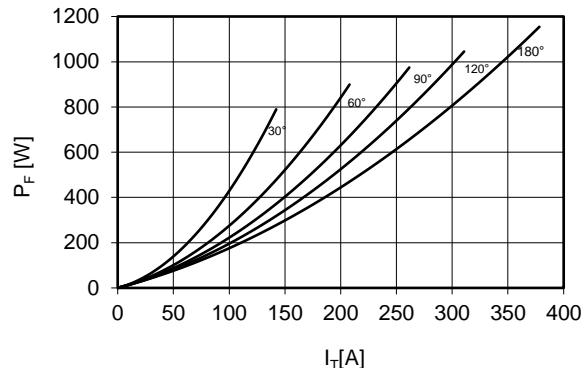
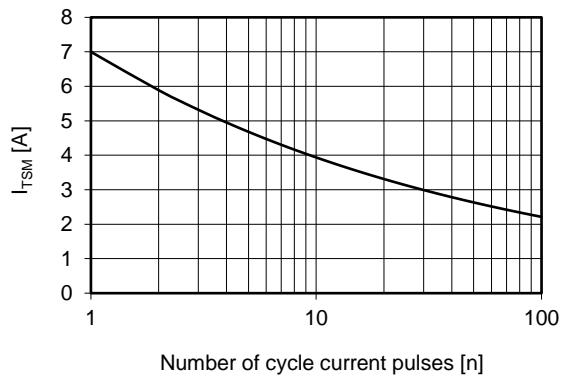
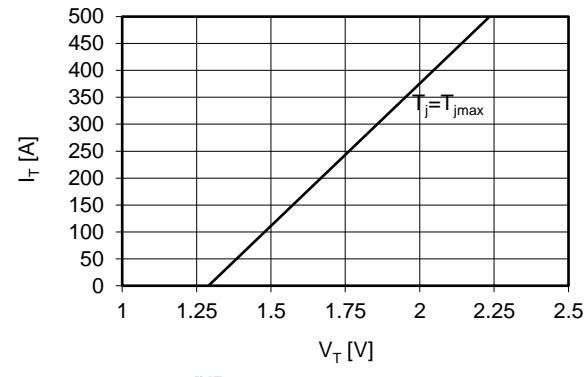
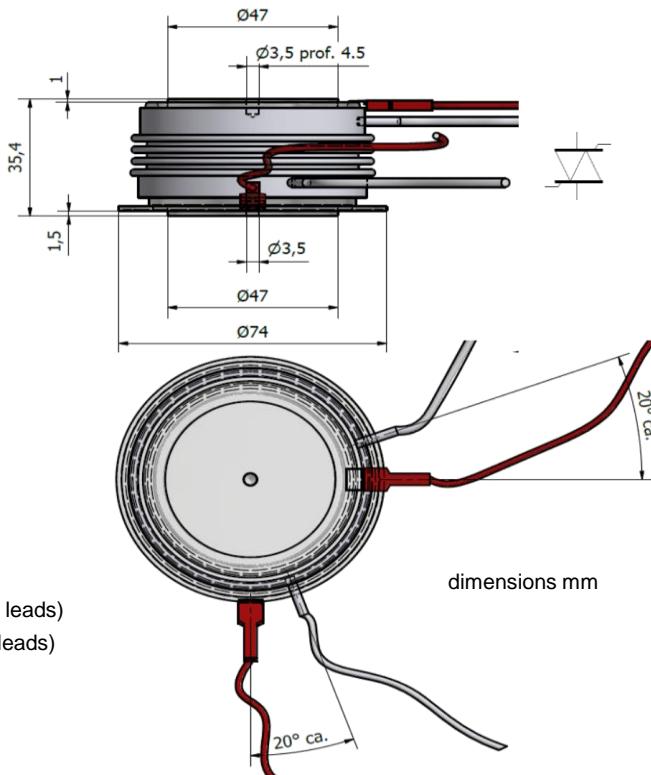
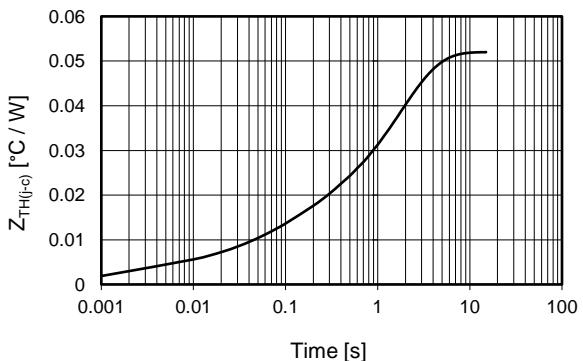
SWITCHING CHARACTERISTICS

dI/dt	Critical rate of rise of on-state current	T _j = 90 °C	100 A/μs
dV/dt	Critical rate of rise of off-state voltage	T _j = T _{jmax}	2000 V/μs
t _q	Turn-off time, typ	T _j = T _{jmax} , I _T = 300 A, dI/dt = -7 A/μs VR = 50 V, VD = 50% V _{DWM} , dV/dt = 20 V/μs	700 μs

THERMAL AND MECHANICAL CHARACTERISTICS

R _{th(j-c)}	Thermal resistance (junction to case)	Double side cooled	0.052 °C/W
R _{th(c-h)}	Thermal resistance (case to heatsink)	Double side cooled	0.008 °C/W
T _{jmax}	Max operating junction temperature		125 °C
T _{stg}	Storage temperature		-40 / 125 °C
F	Clamping force ± 5%		23 kN
	Mass		500 g

Electrical and thermal characteristics are related to one single thyristor

Current rating - sine wave

Power loss - sine wave

**Maximum surge current
d.s. cooled**

On-state voltage drop

Thermal impedance (j-c)


Ordering information GPBP7038-VVGL

VV: blocking voltage / 100 (e.g. 65 for 6500 V)

G: trigger lead type (**S** = straight **T** = twisted **blank** = no leads)

L: trigger lead length x 100mm (**3 - 4 - 5 - 7** **blank** = no leads)

In the interest of product improvement Green Power Solutions reserves the right to change any specification given in this data sheet without notice.